NSN 5961-00-171-0073

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-171-0073 **Inclosure Material:** Metal **Overall Length:** 0.058 inches **Overall Diameter:** 0.120 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.099 inches **Semiconductor Material:** Gallium arsenide **Voltage Rating In Volts Per Characteristic:** 13.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 25.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 95.0 degrees celsius ambient air **Special Features:** power rating; junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded stud and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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